

Part Number: CHP-240

High Power Chip Multi-Mode Fabry-Perot Pulsed Wavelength at 1726nm



Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard Bare Die
- Cost Effective

Application

- Professional Medical
- Home-use Medical



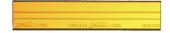
SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.

SemiNex Corporation • 153 Andover Street, Suite 201, Danvers, MA 01923 • 978-326-7700 • sales@seminex.com



Specification

CHP-240



Optical	Symbol	Тур.	Units
Center Wavelength	λ _c	1726	nm (±20)
Output Power CW	Pout	3.0	watts (±10%)
Chip Cavity Length	CL	2500	μm
Emitter Width	W	180	μm
Spectral Width FWHM	Δλ	12	nm
Slope Efficiency	η	0.28	W/A
Fast Axis Div.	ΘΤ	30	deg FWHM
Slow Axis Div.	Θ_{\parallel}	10	deg FWHM
Electrical	Symbol		
Power Conversion Eff.	η	14	%
Operating Current	lop	13	А
Threshold Current	Ітн	1.7	А
Operating Voltage	V _{op}	1.6	V
Mechanical		Range	Units
Operating Temp.**		-40 to 60	°C
Storage Temp.		-40 to 80	°C

*Specified values are rated at a constant heat sink temperature of 20°C.

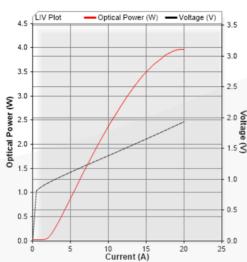
**High temperature operation will reduce performance and MTTF.

Unless otherwise indicated all values are nominal.



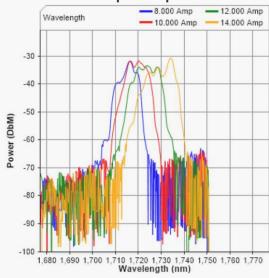
SemiNex Laser Diodes CHP-240 Graphs & Data

Typical COC L-I-V Characteristics



2.0 Voltage (V)

Typical COC Output Spectrum

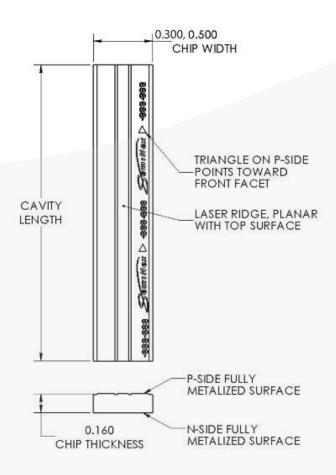






Mechanical Drawing





CHIP ATTRIBUTES

APERTURE WIDTH (µm)	Single Mode (4, 5) ± 1 Multi Mode (50, 95, 180, 350) ± 3	
CHIP WIDTH (µm)	300, 500 ± 10	
THICKNESS (µm)	160 ± 10	
CAVITY LENGTH (µm)	Varies ± 10	

P METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	50	± 10
Pt	125	± 25
Au	250	± 50

N METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	30	± 10
Pt	125	± 25
Au	400	± 40

All statements, technical information and recommendations related to the product herein are based upon information believed to be reliable or accurate. The accuracy or completeness herein is not guaranteed, and no responsibility is assumed for any inaccuracies. The user assumes all risks and liability whatsoever in connection with the use of a product or its application. SemiNex Corporation reserves the right to change at any time without notice the design, specification, deduction, fit or form of its described herein, including withdrawal at any time of a product offered for sale herein. Users are encouraged to visit www.seminex.com for the latest data. SemiNex Corporation makes no representations that the products herein are free from any intellectual property claims of others. Please contact SemiNex for more information. 2024 SemiNex Corporation

